TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA7358AP

FM Front-End

The TA7358AP is designed for a FM front-end application,which is suitable to a portable radio or a radio cassette. Comparing with conventional types, supply voltage dependence, overload characteristics and spurious radiation characteristics are improved.

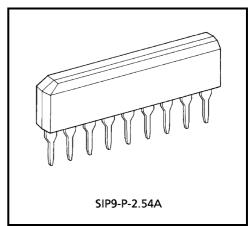
Features

- Wide supply voltage range : $V_{CC} = 1.6 \sim 6.0 V$
- Excellent supply voltage dependence of local oscillator : Oscillation stop

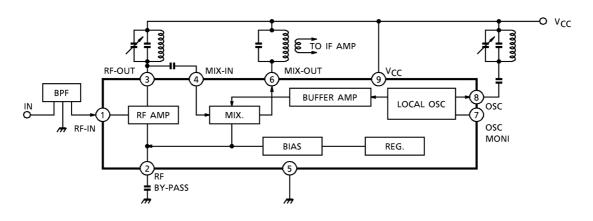
 $V_{CC} = 0.9V$ (typ.)

- Improved inter-modulation characteristics by double balanced type mixer circuit.
- Low spurious radiation.
- Built-in clampping diode for the local oscillator output.

Block Diagram



Weight: 0.92g (typ.)



Explanation Of Terminals (terminal voltage is DC voltage at Ta = 25° C, V_{CC} = 5V, and no signal)

Pin No.	Symbol	Internal	Terminal Voltage (V)	
1	FM-RF IN	3	0.8	
2	BY PASS		1.5	
3	FM-RF OUT		5.0	
4	MIX IN	GND (S	1.5	
5	GND	—	0	
6	MIX OUT	cf. pin(4)	5.0	
7	OSC MONITOR	V _{CC} (0)	4.3	
8	OSC		5.0	
9	V _{CC}	—	5.0	

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Supply voltage	V _{CC}	8	V
Power dissipation	P _D (Note)	500	mW
Operating temperature	T _{opr}	-25~75	°C
Storage temperature	T _{stg}	-55~150	°C

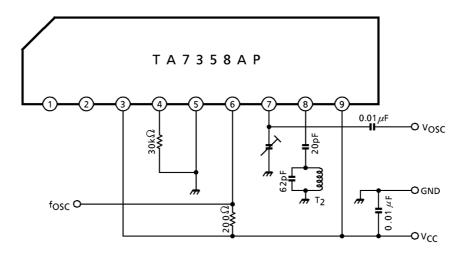
(Note) Derated above 25°C in the proportion of 4mW / °C.

Electrical Characteristics (V_{CC} = 3V, f = 83MHz, f_m = 1kHz, Δf = ±22.5kHz, Ta = 25°C)

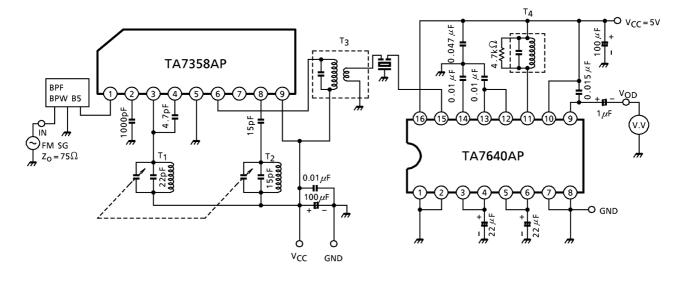
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Supply current		Icc	2	V _{in} = 0	_	5.2	8.0	mA
-3dB limiting sensitivity		V _{in(lim)}	2	_	_	3.0	7.0	dBµV EMF
Quiescent sensitivity		QS	2	_	_	11.0	_	dBµV EMF
Conversion gain		G _C	_	_	_	31	_	dB
Local OSC voltage		V _{OSC}	1	f _{OSC} = 60MHz	90	165	220	mV _{rms}
Pin (1) impedance	Parallel input resistance	r _{ip} 1	3		_	57	_	Ω
Pin (3) impedance	Parallel output resistance	r _{op} 3		f = 83MHz	_	25	_	kΩ
	Parallel output capacitance	c _{op} 3	- 3		_	2.0	_	pF
Pin (4) impedance	Parallel input resistance	r _{ip} 4			_	2.7	_	kΩ
	Parallel input capacitance	c _{ip} 4	- 3		_	3.3	_	pF
Pin (6) impedance	Parallel output resistance	r _{op} 6		((0.7)))	-	100	_	kΩ
	Parallel output capacitance	c _{op} 6	- 3	f = 10.7MHz	_	4.8	_	pF
Local OSC stop voltage		V _{stop}	1	_	—	0.9	1.3	V



Test Circuit 1



Test Circuit 2



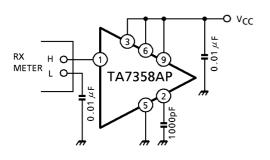
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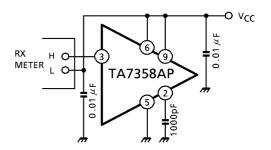
Test Circuit 3

Input output impedance

(1) r_{ip1}, c_{ip1}

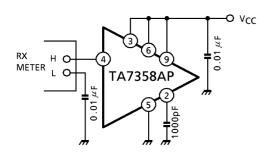
(2) r_{op3}, c_{op3}

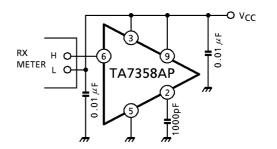




(3) r_{ip4}, c_{ip4}

(4) r_{op6}, c_{op6}





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Test Circuit Coil Data (Japan band for 76.0MHz to 108.0MHz)

Coil	f _o	Qo	Turns	Capacitance	
T ₁ RF coil	100MHz	100	0.5mm ϕ 2 $\frac{1}{4}$ T Center tap (Japan band)	15pF (external)	
T ₂ OSC coil	100MHz	100	0.5mm ϕ 2 $\frac{1}{2}$ T (Japan band)	15pF (external)	
T ₃ IFT coil	10.7MHz	115	(1)–(3) 12T (4)–(6) 1T Wire 0.12mm∳ UEW SUMIDA ELECTRIC Co., LTD 5764 or equivalent	75pF	Vcc Pin ® (BOTTOM VIEW)
T ₄ Quad coil	10.7MHz	150	(4)–(6) 14T Wire 0.12mm∳ UEW SUMIDA ELECTRIC Co., LTD 44M–933A or equivalent	47pF	(BOTTOM VIEW)

Band pass filter (BPF) SOSHIN ELECTRIC Co., LTD. BPWB5 Tuning cpacitor ALPS ELECTRIC Co., LTD. CB41EL933

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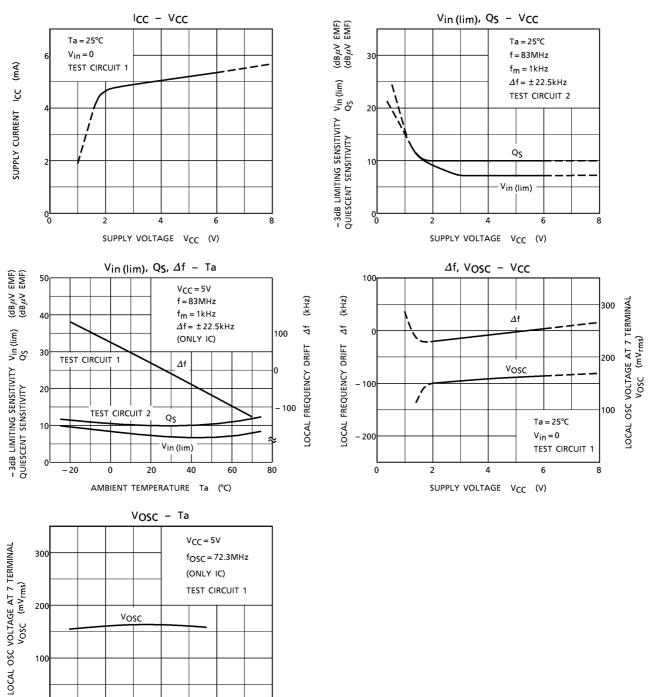
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AMBIENT TEMPERATURE Ta (°C)

80

120

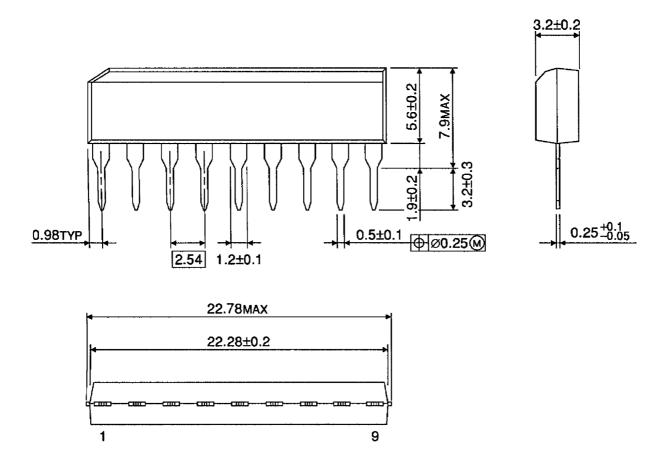


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Package Dimensions

SIP9-P-2.54A

Unit : mm



Weight: 0.92g (typ.)

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